

INVERTERS

Fixed dc $\longrightarrow$ Variable AC
(V_o, f_o)

* Classification of Inverters $\rightarrow$

(1) Voltage Source Inverter (VSI) $\rightarrow$

* 1 ϕ Half bridge Inverter.

* 1 ϕ Full bridge inverter.

* 3 ϕ VSI

$\rightarrow$ Sq wave inverter

$\rightarrow$ PWM inverter.

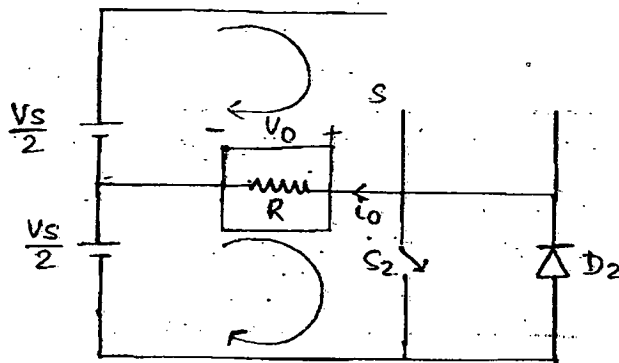
(2) Current source inverter (CSI) -

(3) Series inverter

(4) Parallel inverter.

(1) Voltage source inverter (VSI) $\rightarrow$

(a) 1- ϕ half bridge inverter $\rightarrow$



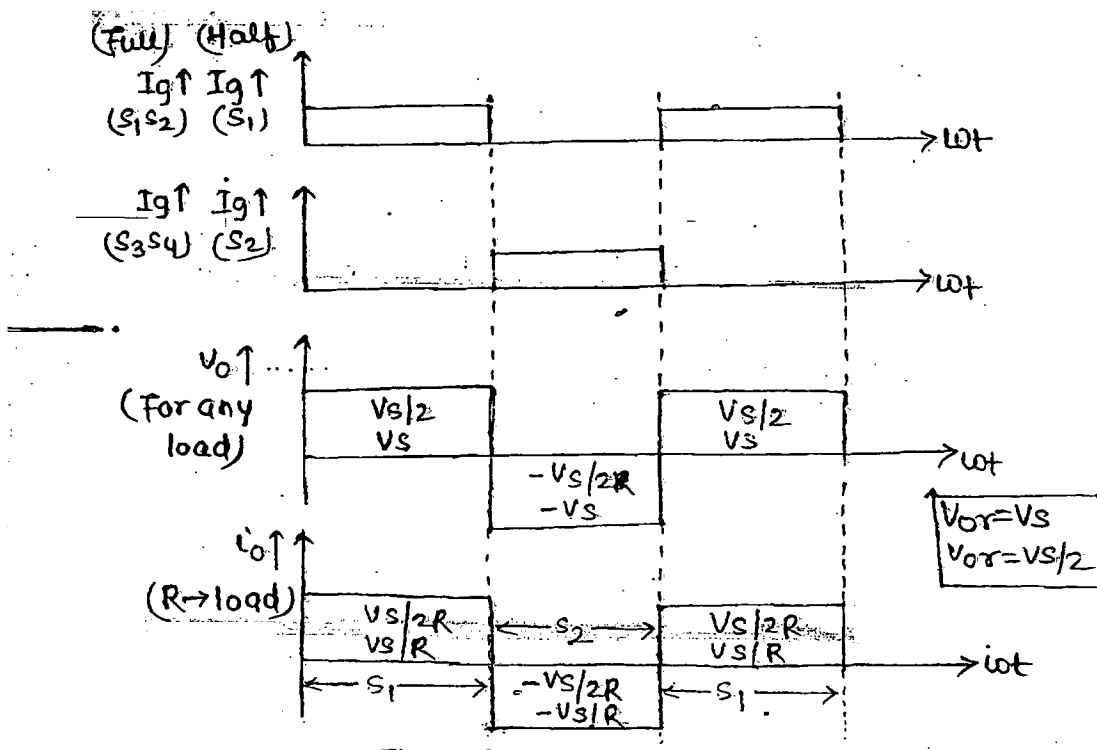
By the use of Fourier Series

$$V_o = \sum_{n=1,3,5,\dots}^{\infty} \frac{2V_s}{n\pi} \sin n\omega t$$

$$V_{on} = \frac{2V_s}{n\pi} \sin n\omega t$$

$$V_{on} = \frac{\sqrt{2}V_s}{n\pi}$$

$$V_{o1} = \frac{\sqrt{2}V_s}{\pi}$$



$$g = \frac{V_{o1}}{V_{or}} = \frac{\sqrt{2} V_s}{\pi} \cdot \frac{\pi}{V_s/2}$$

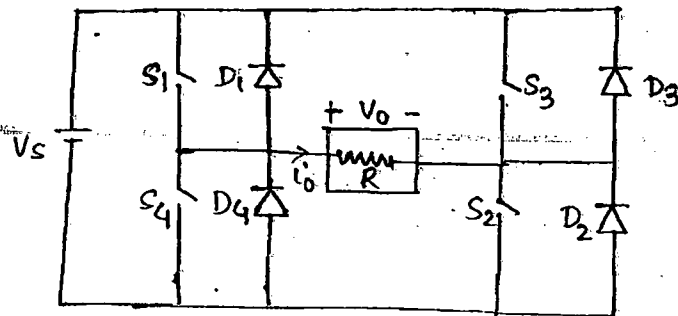
$$g = \frac{2\sqrt{2}}{\pi}$$

$$THD = \left(\frac{1}{g^2} - 1 \right)^{1/2}$$

$$THD = 48.34\%$$

- * For the true power, only R is presents & Hence f/b diode will not conducts. They will conduct only in case of -ve power
- * which is found only in reactive elements (L & C)
- * The shape of the V_o is not depends on the load, but the current waveform is depend on load.

(1) 1-φ full bridge inverter →



$$\begin{aligned} S_1 S_2 &\rightarrow \text{ON} \\ V_o &\rightarrow V_s \\ i_o &\rightarrow V_s/R \end{aligned}$$

$$\begin{aligned} S_3 S_4 &\rightarrow \text{ON} \\ V_o &\rightarrow -V_s \\ i_o &\rightarrow -V_s/R \end{aligned}$$

$$V_o = \sum_{n=1,3,5,\dots}^{\infty} \frac{4V_s}{n\pi} \sin n\omega t$$

$$V_{on} = \frac{4V_s}{n\pi} \sin n\omega t$$

$$V_{on} = \frac{2\sqrt{2}V_s}{n\pi}$$

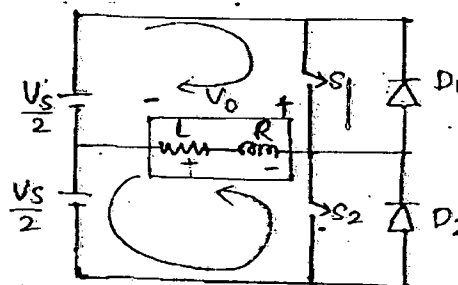
$$V_{o1} = \frac{2\sqrt{2}V_s}{\pi}$$

$$g = \frac{V_{o1}}{V_s} = \frac{2\sqrt{2}V_s}{\pi V_s}$$

$$g = \frac{2\sqrt{2}}{\pi}$$

$$\text{THD} = 48.34\%$$

1-φ Half bridge inverter (Other load) →



mode (1) :- $S_1 \rightarrow \text{ON}$

$$V_o = \frac{V_s}{2}, V_o+, i_o+, (P+)$$

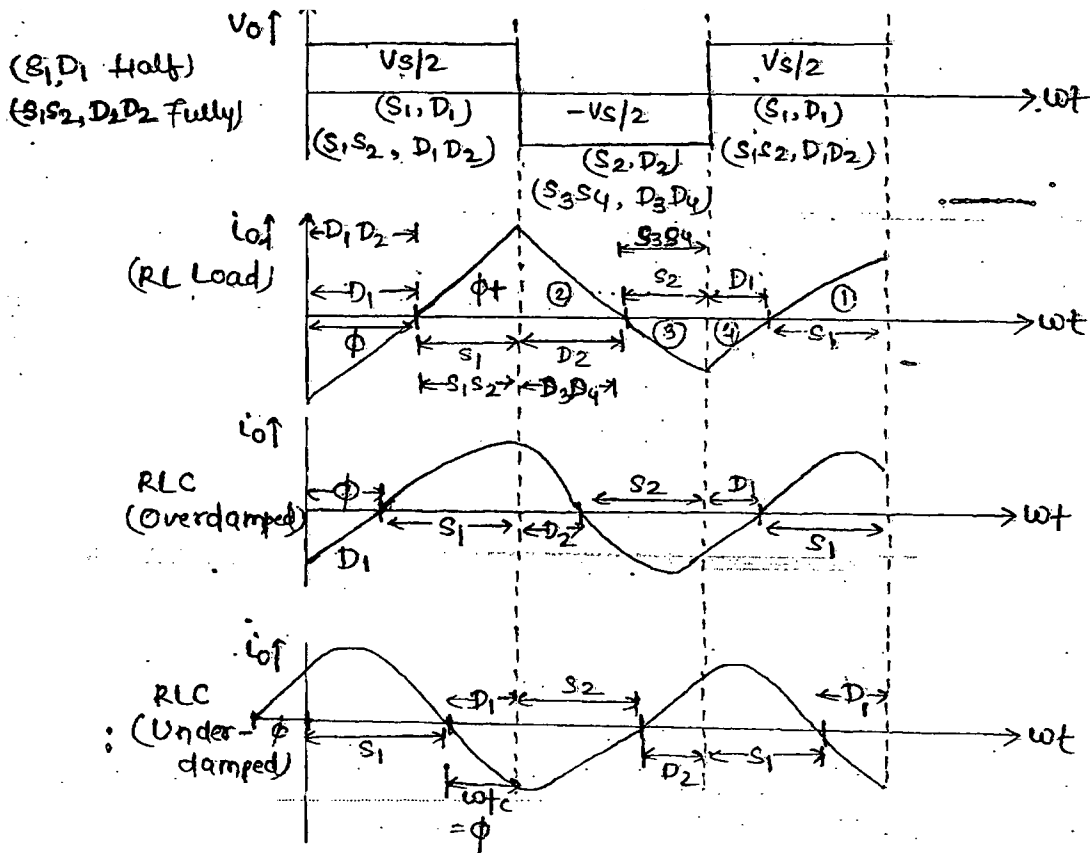
Source $\xrightarrow{P}$ load
($I^2R, \frac{1}{2}Li^2$)

$L \rightarrow$ stores energy

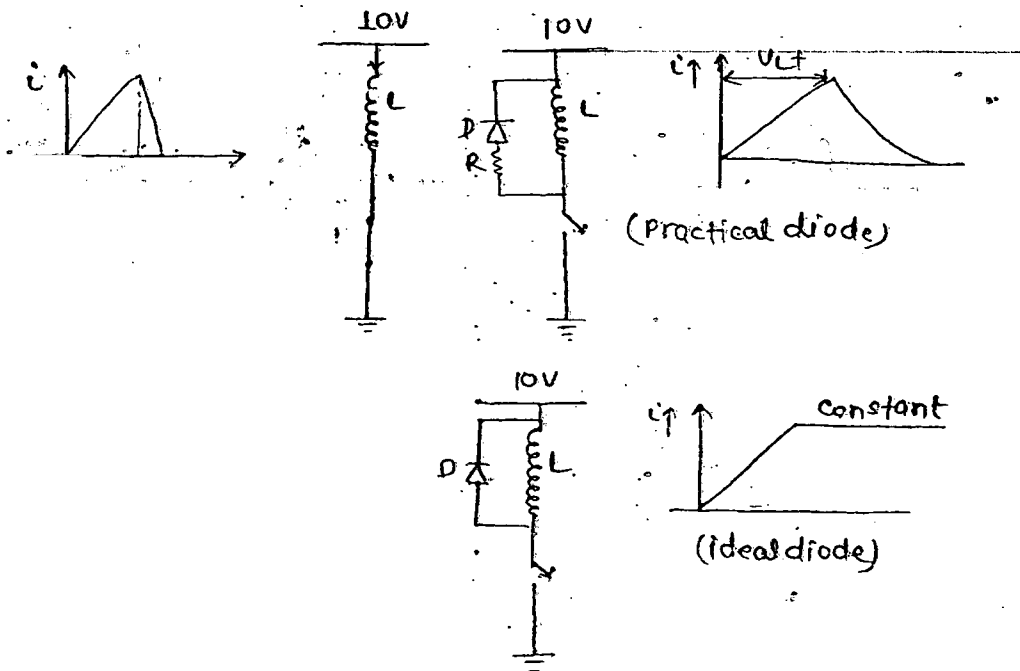
mode (2) :- $D_2 \rightarrow \text{ON}$

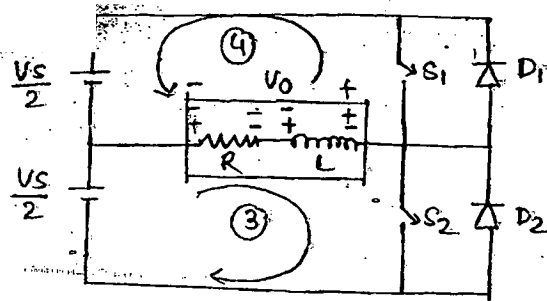
$$\frac{1}{2}Li^2 \rightarrow \text{Source } I^2R$$

$L \rightarrow$ releasing energy



(1) RL Load $\rightarrow$ After reaching steady state, i_o lags by ϕ by $\phi = \tan^{-1}\left(\frac{\omega L}{R}\right)$





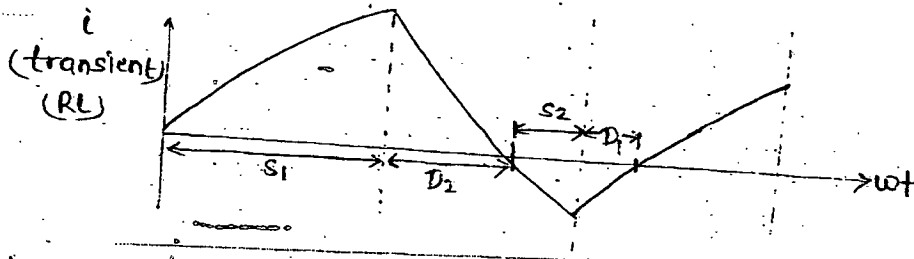
mode ③ → $S_2 \rightarrow \text{ON}$

$$V_0 = -\frac{V_s}{2}, V_0^-, i_0^- \quad (P+)$$

Source $\xrightarrow{P}$ load ($i^2 R$ & $\frac{1}{2} Li^2$)
 $L \rightarrow$ stores energy

mode ④ → $D_1 \rightarrow \text{ON}$

$\frac{1}{2} Li^2 \rightarrow$ source & $i^2 R$
 $L \rightarrow$ releasing energy



* Inductive load will draw dc component at the beginning.

V_0	I_0	P	device
+	+	+	S_1
+	-	-	D_1
-	-	+	S_2
-	+	-	D_2

lagging load $\rightarrow$ diode

leading load $\rightarrow$ switch

2. RLC (Overdamped) $\rightarrow$ ($X_L > X_C$)

i_o lags v_o by $\phi = \tan^{-1} \left(\frac{X_L - X_C}{R} \right)$

$$\boxed{\phi = \tan^{-1} \left(\frac{X_L - X_C}{R} \right)}$$

Forced Comm. is required.

(3) RLC (Underdamped) $\rightarrow$

$$X_C > X_L$$

i_o lags v_o by $\phi = \tan^{-1} \left(\frac{X_L - X_C}{R} \right)$

i_o leads v_o by $\boxed{\phi = \tan^{-1} \left(\frac{X_C - X_L}{R} \right)}$

Load Comm. is required

$$* * \boxed{\omega t_c = \phi}$$

$$t_c = \frac{\phi}{\omega} = \frac{\tan^{-1} (X_C - X_L)}{R\omega}$$

If $t_c > t_q$; load Comm. is successful

$t_c < t_q$; load Comm. is fails

$\therefore$ we require forced Comm.

$$\bar{V}_{on} = \frac{2V_s}{n\pi} \cdot \sin \omega t \quad (\text{Any load})$$

Let us consider RLE load;

$$i_{on} = \frac{V_{on}}{Z_n}$$

$$= \frac{V_{on}}{|Z_n| \angle \phi_n}$$

$$= \frac{V_{on} \angle -\phi_n}{|Z_n|}$$

$$\boxed{i_{on} = \frac{2V_s}{n\pi |Z_n|} \cdot \sin(n\omega t - \phi_n)}$$

$$\text{where } Z_n = R_n + j(X_{Ln} - X_{Cn})$$

$$Z_n = |Z_n| \angle \phi_n$$

$$|Z_n| = \sqrt{R^2 + (X_{Ln} - X_{Cn})^2}$$

$$\phi_n = \tan^{-1} \left(\frac{X_{Ln} - X_{Cn}}{R} \right)$$

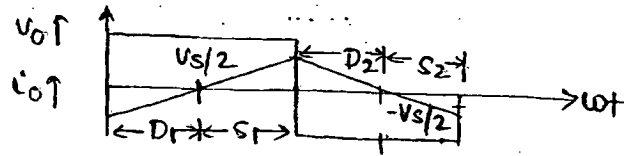
For pure inductive load

$$|Z_n| = X_n = n\omega L$$

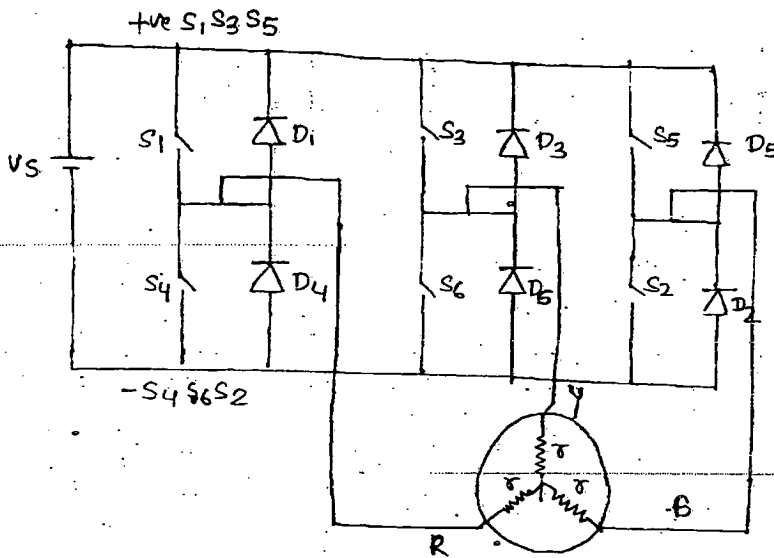
$$\phi_n = 90^\circ$$

$$i_{on} = \frac{2V_s}{n\pi(n\omega L)} \sin(n\omega t - 90^\circ)$$

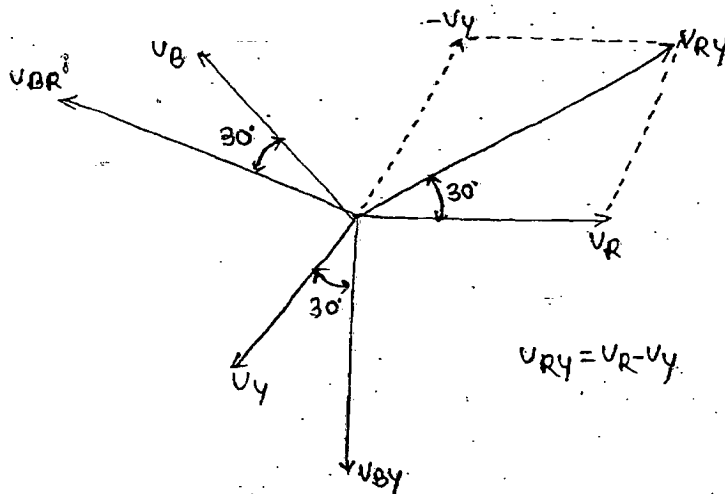
$$i_{on} \propto \frac{1}{n^2}$$

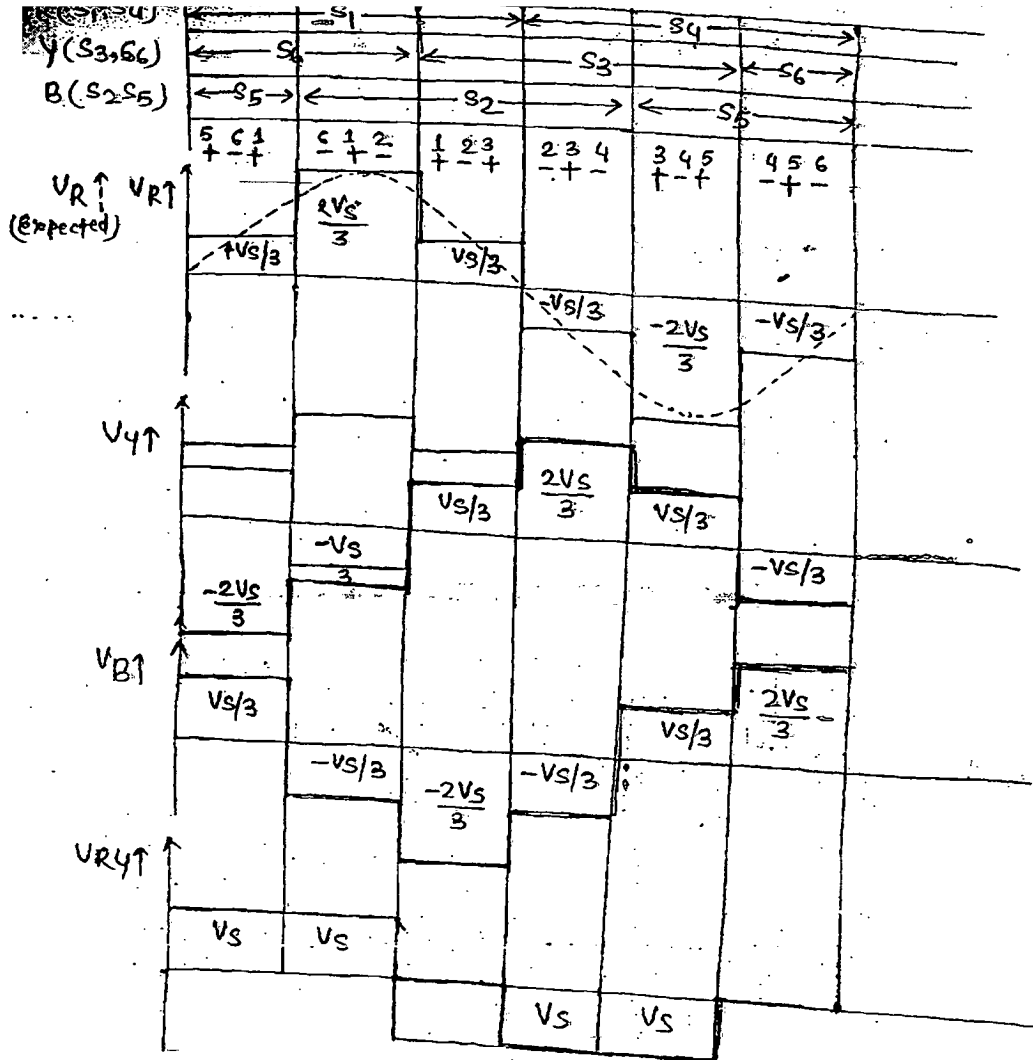


(iii) 3-φ VSI →



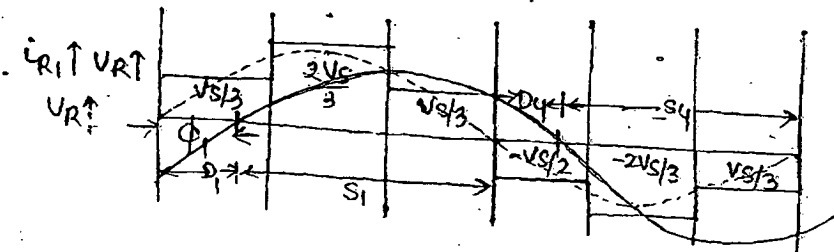
* In 180° VSI the conduction angle of switch & its antiparallel diode is 180°.



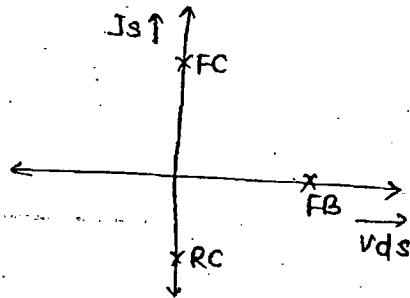


$$(V_{R4})_{RMS} = V_s \left(\frac{2\pi}{3} \right)^{1/2} \frac{1}{\pi}$$

$$V_L = \sqrt{\frac{2}{3}} V_s$$

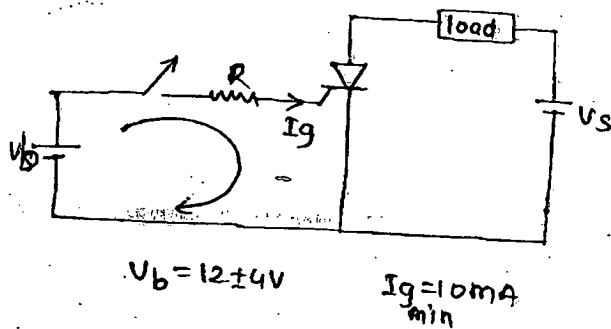


Question



ans(b)

(2-1)



$$I_{gmin} \leq I_g \leq I_{gmax}$$

For worst condⁿ
min^m gate current

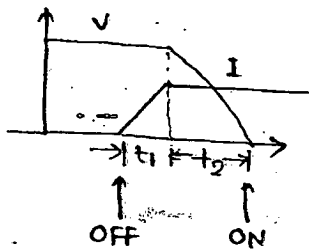
$$= \frac{(V_b)_{min}}{R}$$

$$= \frac{12-4}{R} = \frac{8}{R} \geq I_{gmin}$$

$$\therefore R \leq \frac{8}{I_{gmin}}$$

$$R \leq \frac{8}{(10) \times 10^{-3}} \quad \boxed{R \leq 800 \Omega}$$

(2-2)



Turn on process

$$E_{t1} = \int_0^{t_1} V \cdot \frac{I}{t_1} t dt = \frac{1}{2} V I t_1$$

$$E_{t2} = I (V t)_{area}$$

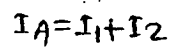
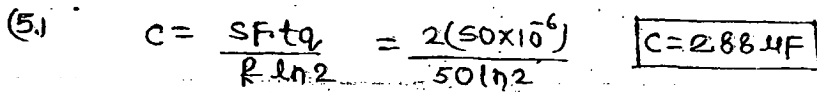
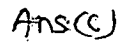
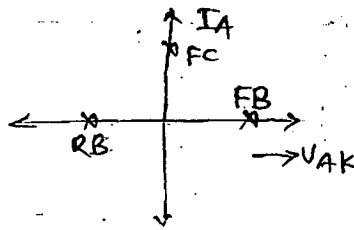
$$= I \left(\frac{1}{2} \right) V t_2$$

$$= \frac{1}{2} V I t_2$$

$$E_{t1} = V (I t)_{area} = I \cdot \frac{V}{2} \cdot t_2$$

$$\boxed{\text{Total } E = \frac{1}{2} V I (t_1 + t_2)}$$

ans(a)



$$I_1 = \frac{V_S}{R_1} (1 - e^{-t/\tau_1}) = \frac{100}{20} (1 - e^{-40t})$$

$$I_1 = 5(1 - e^{-40t})$$

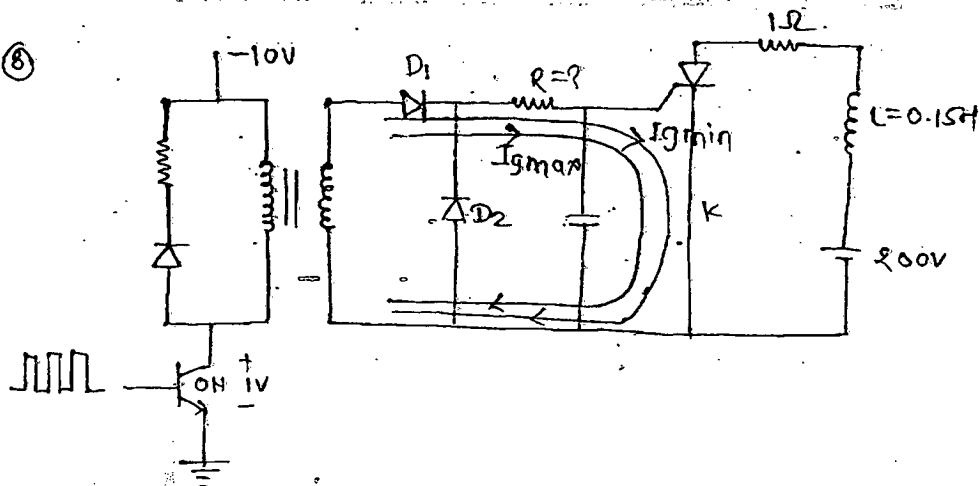
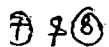
$$I_2 = \frac{V_S}{R_2} = \frac{100}{5 \times 10^3} = 20 \times 10^{-3}$$

$$T_1 = \frac{L_1}{R_1} = \frac{1}{40}$$

$$I_A = I_1 + I_2$$

$$I_L = 5(1 - e^{-40t}) + 20 \times 10^{-3}$$

$$t_{\min} = 150 \mu s$$



$$9V = 1V + (I_{gmax} R) + 1V$$

$$R \geq 46.67 \Omega$$

$$9V = 1V + (I_{gmin} R) + 1V$$

$$R \leq 70 \Omega$$

If we consider both then $46.6 \leq R \leq 70 \Omega$

Ans. (c) 47Ω

(8.) Volt sec rating of pulse $X_{mer} = 10 \times t_{g_{pw}}$
 $t_{g_{pw}} > t_{min}$

$g_{pw} = \text{Gate}$

Pulse width

$$I_A = \frac{V_S}{R} (1 - e^{-t/T})$$

↓

$$I_L = \frac{200}{1} (1 - e^{-t_{min}/0.15})$$

$$t_{min} = 187.45$$

$$= 10 \times t_{g_{pw}}$$

$$= 10 \times t_{min} = 10 \times 187.45 \mu s$$

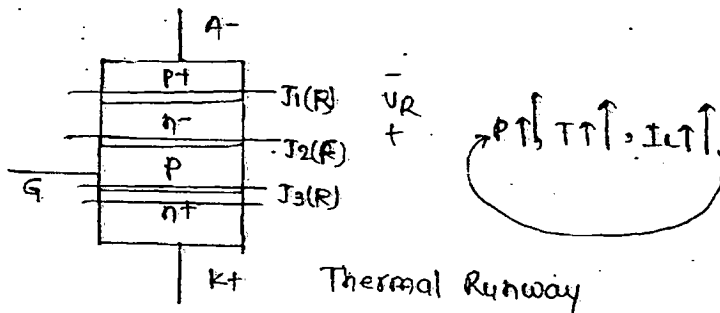
Volt. sec rating of pulse $X_{mer} > 1870.45 \mu s$

i.e. $2000 \mu s$

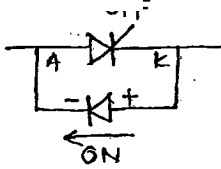
(9.) (c.) (10.) MOSFET (11.) (a.) (12.) (a.) (13.) (c.) (14.) $I_g \uparrow$ OR $\frac{d}{dt} I_g \uparrow$ (d)

(15.) (c.) (16.) (c.) (17.) (d.)

(17.)



(18.)



$$V_R \uparrow, t_R \downarrow, \therefore P \uparrow$$

$$V_R \downarrow, t_R \uparrow, \therefore P \downarrow$$

ans(b)

$$(19.) \quad I_{S/2} = \sqrt{2} I_{S1} \Rightarrow 3000 = \sqrt{2} I_{S1}, \quad I_{S1} = 2121.3 \text{ A}$$

$$(20.) \quad (I_T)_{\text{avg. Rating}} = \frac{(I_T)_{\text{RMS Rating}}}{\text{FF}}$$

$$\text{FF} = \frac{I_T(\text{avg})}{I_{or}} = \frac{I_{or}}{I_o}$$

$$= \frac{V_{or}/R}{V_o/R}$$

$$= \frac{V_{or}}{V_o} = \frac{V_{or}}{\sqrt{2.2\pi} \left[(1-\alpha) + \frac{1}{2} \sin 2\alpha \right]^{1/2}}$$

$$= \frac{V_{or}}{\frac{V_{or}}{2\pi} \cos \alpha}$$

$$= 3.98$$

$$(I_T)_{\text{avg Rating}} = \frac{35}{3.98}$$

$$= 8.84$$

(21) more than 20A (22) (B) (23) (b)

Conventional Q. (1) (b)

Heat sink

J - C - S - A

$$T_j = 125^\circ\text{C}; \quad T_{si} = 70^\circ\text{C}$$

$$PAV_1 = \frac{T_j - T_{si}}{\theta_{jc} + \theta_{cs}} = \frac{125 - 70}{0.16 + 0.08} = 229.16 \text{ W}$$

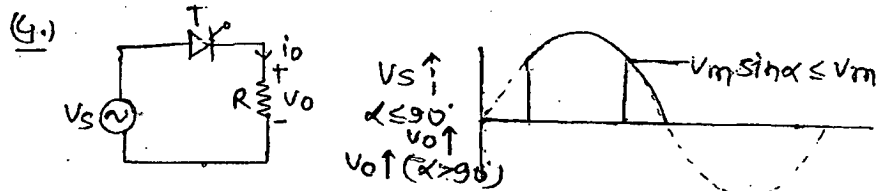
$$\downarrow T_{s2} = 60^\circ\text{C} \text{ (cool down)}$$

$$\therefore PAV_2 = \frac{125 - 60}{0.16 + 0.08} = 270.8 \text{ W}$$

$$\% \text{ increase in Rating} = \frac{\sqrt{PAV_2} - \sqrt{PAV_1}}{\sqrt{PAV_1}} \times 100 = 8.79\%$$

Chap. (2.)

(2.) (b.) (3.) $PIV = 2V_m = 2(50)\sqrt{2} = 100\sqrt{2}$



If $\alpha \geq 90^\circ$, $[V_o(\omega t)]_{peak} = V_m$

If $\alpha < 90^\circ$, $[V_o(\omega t)]_{peak} = V_m \sin \alpha = 230V$

$\Rightarrow 230\sqrt{2} \sin \alpha = 230$

$\Rightarrow 230(\sqrt{2}) \sin \alpha = 230$

$\sin \alpha = \frac{1}{\sqrt{2}}$

$\alpha = 45^\circ$

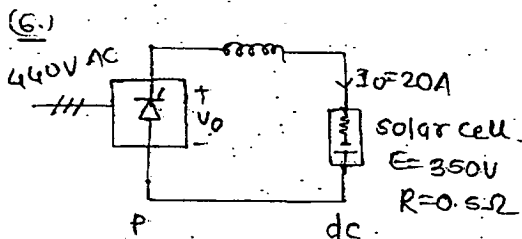
(5.) $\alpha = 60^\circ$

$FDF = \cos \alpha$

$= \cos 60^\circ = 0.5$

$PF = \cos \alpha = 0.478$

[Ans. (c)]



AC $\leftarrow$ DC
INV ($\alpha > 90^\circ$) (V_o)

$V_o = -E + I_o R$

$\frac{3V_m}{\pi} \cos \alpha = -E + I_o R$

$\frac{3(440\sqrt{2})}{\pi} \cos \alpha = -350 + (20 \times 0.5)$

$\alpha = 125^\circ$

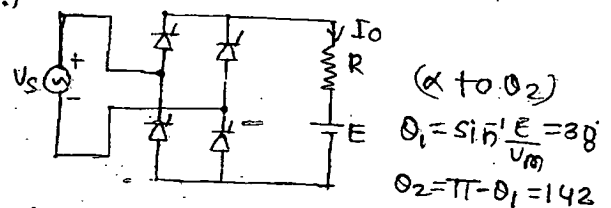
$\alpha \geq 90^\circ$

$\alpha + \omega t_c = \pi$

$\omega t_c = \pi - \alpha = 180^\circ - 125^\circ$

$\omega t_c = 55^\circ$

(7.)



$I_o = \frac{1}{\pi R} [V_m (\cos \alpha - \cos \theta_2) - E (\theta_2 - \alpha)]$

$= \frac{1}{\pi R} [V_m (\cos \theta_1 - \cos \theta_2) - E (\theta_2 - \theta_1)]$

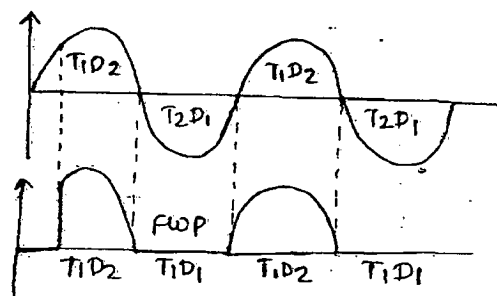
$= \frac{E (142 - 38)}{18t}$

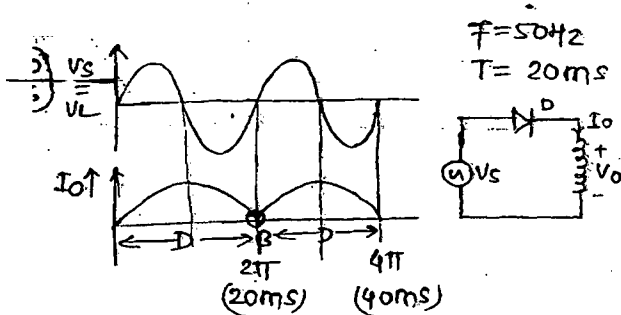
$I_o = 11.9A$

(8.) $\alpha = 25^\circ$, $\phi = 10^\circ$

$FDF = \cos \left(\alpha + \frac{\phi}{2} \right) = 0.866$

(9.)

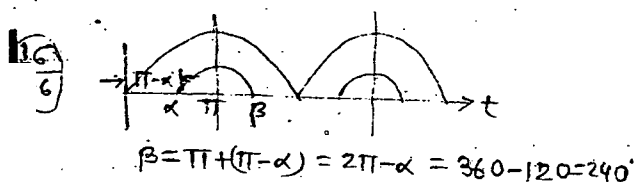
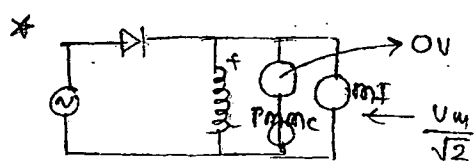




$\left(\frac{14}{46}\right) V_s = 100\sqrt{2} \sin(100\pi t)$
 $I_s = 10\sqrt{2} \sin(100\pi t - \frac{\pi}{3}) + 5\sqrt{2} \sin(300\pi t + \frac{\pi}{4}) + 2\sqrt{2} \sin(500\pi t - \frac{\pi}{6})$
 $P = V_{sr} \cdot I_{sr} \cos \alpha = 100(2) \cos(\pi/3) = 100$

$I_o = \frac{V_m}{\omega L} (1 - \cos \omega t)$
 $= \frac{V_m}{\omega L} - \frac{V_m}{\omega L} \cos \omega t$
 $(I_o)_{avg} = \frac{V_m}{\omega L}, I_{or} = 1.225 \frac{V_m}{\omega L}$

$I_{or} = \sqrt{\left(\frac{V_m}{\omega L}\right)^2 + \left(\frac{V_m}{\sqrt{2}\omega L}\right)^2} = 1.225 \frac{V_m}{\omega L}$



1) AC $\leftarrow$ DC
 INV ($\alpha > 90^\circ$) (V_o)

$V_o = -E + I_o R \quad I_o = \frac{V_o + E}{R}$

$V_o = \frac{3V_m L}{\pi} \cos \alpha; \alpha = 90.001 = 90 +$
 $V_o = 0$ (Because Inv is not possible at 90°)

$I_o = \frac{0 + 400}{10} = 40\text{A}$

KVA rating of Tr = $\sqrt{2} V_{sr} \cdot I_{sr}$

$I_{sr} = \sqrt{\frac{2}{3}} I_o$

$Tr = \sqrt{2} \cdot 400 \times \sqrt{\frac{2}{3}} I_o$

$Tr = 22.6\text{KVA}$

$\left(\frac{15}{46}\right) PF = g \cdot FDF \quad g = \frac{I_{s1}}{I_{sr}} = \frac{10}{\sqrt{10^2 + 5^2 + 2^2}}$

$PF = \frac{10}{\sqrt{129}} \cos 60^\circ = 0.44$

$\left(\frac{18}{47}\right) V_o = \frac{V_m}{\pi} (1 + \cos \alpha); (V_o)_{max} = \frac{2V_m}{\pi} = I_f (100 + R_s)$
 $\frac{2 \cdot 100\sqrt{2}}{\pi} = (1 \times 10^{-3}) (100 + R_s); R_s = 89.9\text{K}$

$\left(\frac{19}{47}\right) RLE \text{ load 2 pulse, } \alpha = 110^\circ, \mu = ?$

$\Delta V_{do} = \frac{V_{do}}{2} [\cos \alpha - \cos(\alpha + \mu)] = 4fL_s I_o$

$V_{do} = \frac{2V_m}{\pi}; V_o = -E_g + I_o R_g$ [Because $\alpha > 90^\circ$ Inv]

$V_o = V_o \cos \alpha - 4fL_s I_o \dots (i)$

$I_o = 35.7\text{A} \quad \mu = 8.35^\circ$

Conventional que (2) $\rightarrow$

3 pulse: $V_{do} = \frac{3V_m L}{2\pi}$

$\alpha_{max} = 180 - [\omega t_q + \mu_o] \quad \mu_o = \text{overlap angle at } \alpha =$

$\Delta V_{do} = \frac{V_{do}}{2} [\cos \alpha - \cos(\alpha + \mu)] = 3fL_s I_o$

$\frac{V_{do}}{2} [1 - \cos \mu_o] = 3fL_s I_o$

Because at $\alpha = 0$ (Rec. mode)

$V_o = E_b + I_o R_a \dots (i)$

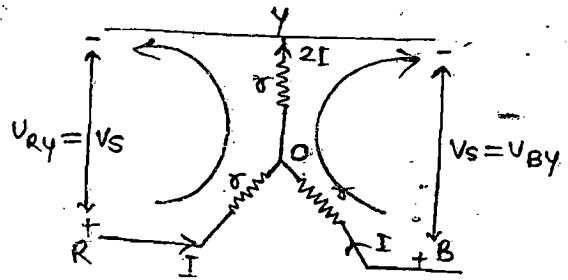
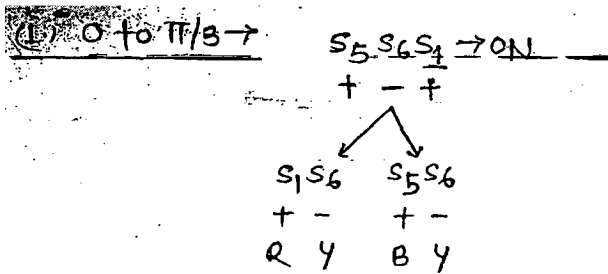
$V_o = V_{do} \cos \alpha = 3fL_s I_o \dots (2)$

$I_o = 14.7\text{A}, \mu_o = 17^\circ$

$\omega t_q = 2\pi f t_q = 2\pi \cdot 50 \cdot 250 \times 10^{-6} \times 180 = 4.5$

$\alpha_{max} = 180 - [\omega t_q + \mu_o] = 180 - [4.5 + 17]$

$\alpha_{max} = 158.5$



By using KVL $\rightarrow$

$$V_S = Ir + 2Ir$$

$$V_S = 3Ir$$

$$Ir = \frac{V_S}{3}$$

$$V_R = +Ir = +\frac{V_S}{3}$$

$$V_Y = -2Ir = -\frac{2V_S}{3}$$

$$V_B = +Ir = +\frac{V_S}{3}$$

$$(V_R)_{rms} = \left[\frac{1}{\pi} \left\{ \left(\frac{V_S}{3} \right)^2 \frac{\pi}{3} + \left(\frac{2V_S}{3} \right)^2 \frac{\pi}{3} + \left(\frac{V_S}{3} \right)^2 \frac{\pi}{3} \right\} \right]^{1/2}$$

$$V_{ph} = \frac{\sqrt{2}V_S}{3}$$

$$I_L = I_{ph} = \frac{V_{ph}}{\frac{\pi}{3}} = \frac{\sqrt{2}V_S}{3\pi} A$$

$$(I_S)_{rms} = \left[\frac{1}{\pi} \left\{ \left(\frac{V_S}{3\pi} \right)^2 \frac{\pi}{3} + \left(\frac{2V_S}{3\pi} \right)^2 \frac{\pi}{3} + \left(\frac{V_S}{3\pi} \right)^2 \frac{\pi}{3} \right\} \right]^{1/2}$$

Switch

$$= \frac{V_S}{3\pi}$$

$$(I_S)_{rms} = \frac{V_S}{3\pi}$$

(1) $V_{ph} = \frac{\sqrt{2}V_S}{3}$ (4) $V_L = \sqrt{3}V_{ph}$

(2) $I_{ph} = \frac{V_{ph}}{\frac{\pi}{3}}$ (5) $P = 3I_{ph}^2 \frac{\pi}{3}$

(3) $(I_S)_{rms} = \frac{I_{ph}}{\sqrt{2}}$

$$P = \frac{3V_{ph}^2}{\pi}$$

The Fourier Series of $V_R = \sum_{n=6k \pm 1}^{\infty} \frac{2V_s}{n\pi} \sin n\omega t$

$n = 1, 5, 7, 11, 13, 17, 19, \dots$

Note:- Even & tripple harmonics are not present.

$g = \frac{3}{\pi}$, THD = 31%

$V_{Rn} = \frac{2V_s}{n\pi} \sin n\omega t \rightarrow \text{Any load}$

Let us consider RLC load in each phase & let $(X_L > X_C)$

$i_{Rn} = \frac{V_{Rn}}{Z_n} = \frac{V_{Rn}}{|Z_n| \angle \phi_n} = \frac{V_{Rn} \angle -\phi_n}{|Z_n|}$

$i_{Rn} = \frac{2V_s}{n\pi |Z_n|} \sin(\omega t - \phi_n)$

$i_{R1} = \frac{2V_s}{\pi |Z_1|} \sin(\omega t - \phi_1)$

* Cond'n angle of each diode

$D \rightarrow \phi = \tan^{-1} \left(\frac{X_L - X_C}{R} \right)$

* Cond'n angle of each switch

$S = (\pi - \phi)$

Fourier Series for line voltages:-

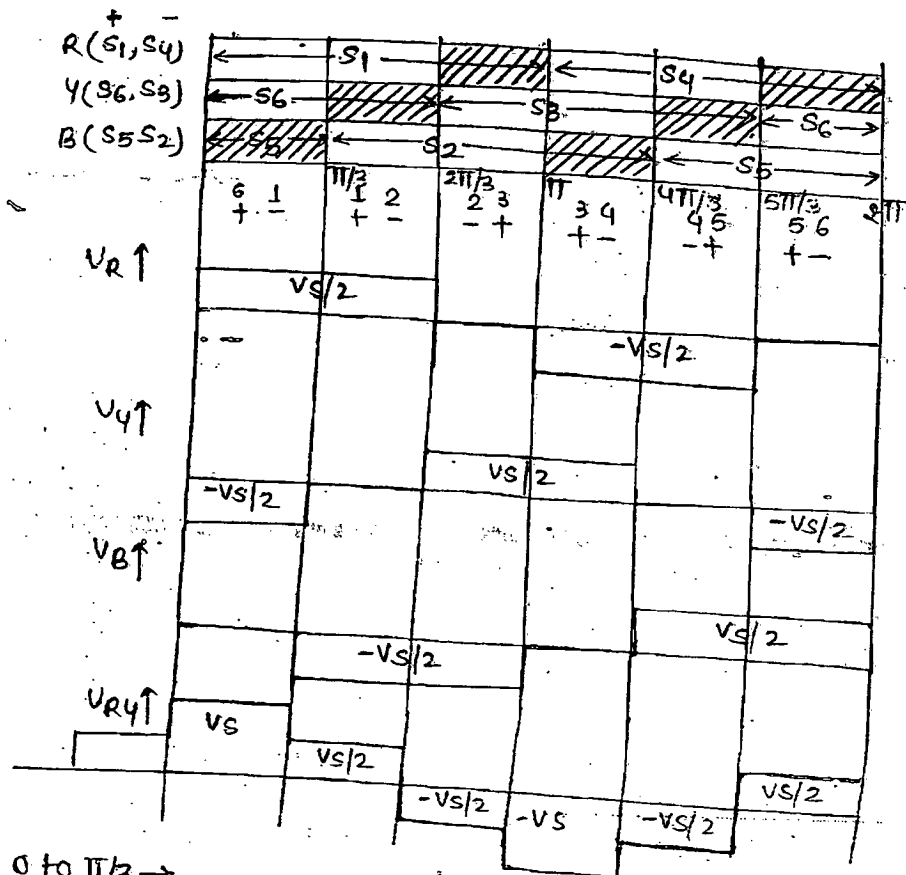
$V_{Ry} = \sum_{\substack{n=1,3,5,\dots \\ n=6k \pm 1}}^{\infty} \frac{4V_s}{n\pi} \sin \frac{n\pi}{3} \sin(\omega t + \frac{n\pi}{6})$

Note:- Even & odd tripple harmonics are not present.

$g = \frac{3}{\pi}$, THD = 31%

Drawback $\rightarrow$ There is a possibility of SC across the supply when the incoming switch is start conducting before the outgoing switch belonging to the same phase stops conducting.

120° VSI → In this case a condⁿ angle of 120° is allotted for each switch & the last 60° is allotted for commutation.



0 to $\pi/3 \rightarrow$

S1, S6 → ON
+ -
R Y

$$V_R = \frac{V_s}{2}, V_Y = -\frac{V_s}{2}, V_B = 0$$

$$* (V_R)_{rms} = \frac{V_s}{2} \left[\frac{2\pi/3}{\pi} \right]^{1/2}$$

$$(V_R)_{rms} = \frac{V_s}{\sqrt{6}}$$

$$* I_{ph} = \frac{V_{ph}}{r}$$

$$* V_L = \sqrt{3} V_{ph}$$

$$* (I_s)_{rms} = \frac{I_{ph}}{\sqrt{2}}$$

$$* P = 3 I_{ph}^2 r = \frac{3 V_{ph}^2}{r}$$

$$V_R = \sum_{n=1,3,5}^{\infty} \frac{2V_s}{n\pi} \cdot \frac{\sin n\pi}{3} \cdot \sin\left(\omega t + \frac{n\pi}{3}\right)$$

$n = 6k \pm 1$

Note:- even & tripple harmonic are not present

$$g = \frac{9}{\pi}, THD = 31\%$$

$$V_{RY} = \sum_{n=1,3,5}^{\infty} \frac{3V_s}{n\pi} \sin n\omega t$$

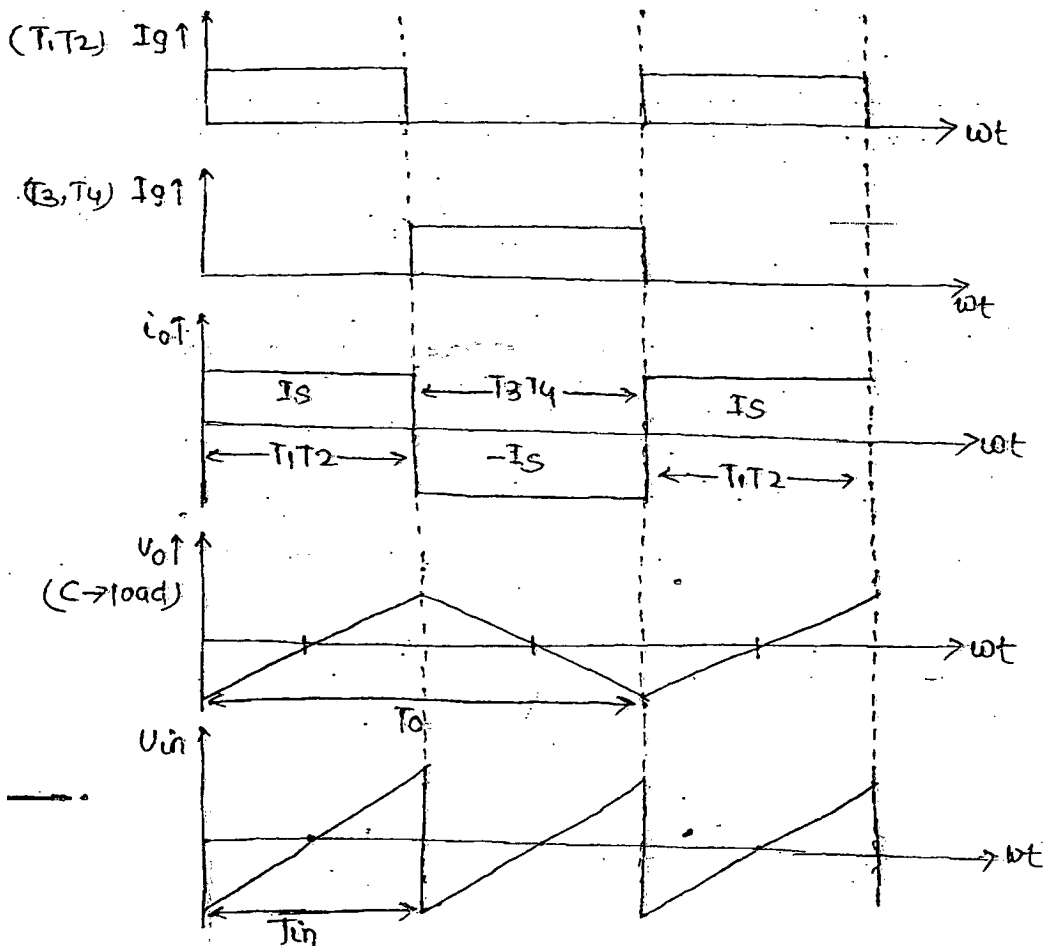
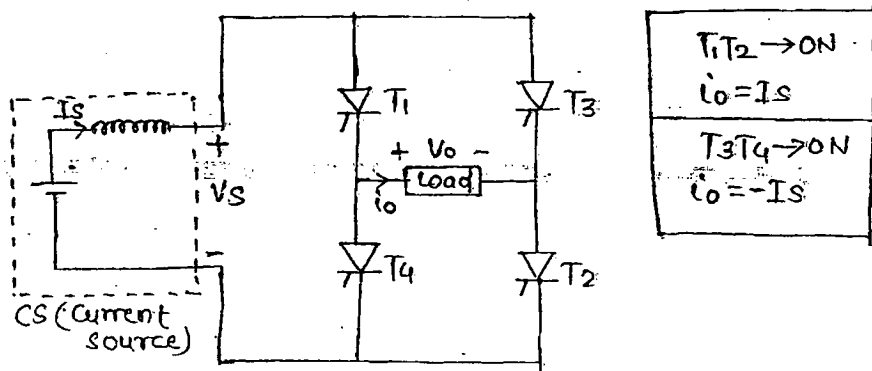
$$n = 6k \pm 1$$

$$n = 1, 5, 7, 11, 13, 17$$

Note $\rightarrow$ even & tripple harmonic are not present.

$$g = \frac{3}{\pi}, \text{THD} = 31\%$$

Current Source Inverter $\rightarrow$ (CSI)



$$i_s = \sum_{n=1,3,\dots}^{\infty} \frac{4I_s}{n\pi} \sin n\omega t$$

$$g = \frac{2\sqrt{2}}{\pi}, \text{ THD} = 48.34\%$$

$$i_{on} = \frac{4I_s}{n\pi} \sin n\omega t$$

Let us consider RLC Load.

$$V_{on} = i_{on} Z_{on} = i_{on} |Z_n| \angle \phi_n$$

$$V_{on} = \frac{4I_s}{n\pi} |Z_n| \sin(n\omega t + \phi_n)$$

eg:- For pure capacitive load; (load comm.)

$$|Z_n| = X_{cn} = \frac{1}{n\omega c}$$

$$\phi_n = -90^\circ$$

$$V_{on} = \frac{4I_s}{n\pi} \cdot \frac{1}{n\omega c} \sin(\omega t - 90^\circ)$$

$$\begin{array}{ccc} T_o = 2T_{in} & & \\ f_{in} & 2f_o & \\ \downarrow & \downarrow & \\ d_c & 4c & \\ f_o = 2f_s & & \end{array}$$

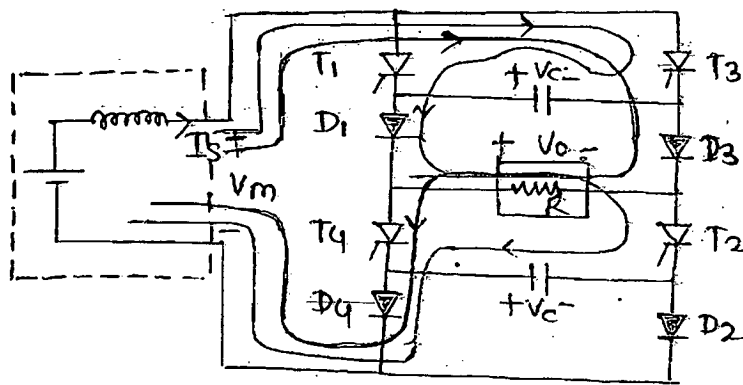
$$V_{on} \propto \frac{1}{n^2}$$

Advantage of CSI →

- (1) Feedback diodes are not req. in CSI.
- (2) Comm. is very simple.
- (3) For capacitive load there is a possibility of load comm.
- (4) Inherently there is SC protection for the supply when the incoming thy. are switched on before the outgoing thy. becomes off.

Disadvantage → * During comm. process the commutating capacitor (load) applies ^{high} rev. vol. across the device therefore the devices having low rev. vol. blocking capability such as GTO's, IGBT's & other transistors are generally not preferred in CSI.

* If the capa. comm. capacitor is connected directly across the load then it will be continuously discharging through the load. To avoid this prob we must connect blocking diode b/n the load & commutating capacitor as shown in fig. given below.



It is also called as
ASCI
(Auto sequential
commutated inverter)

mode(1) →

mode(2) →

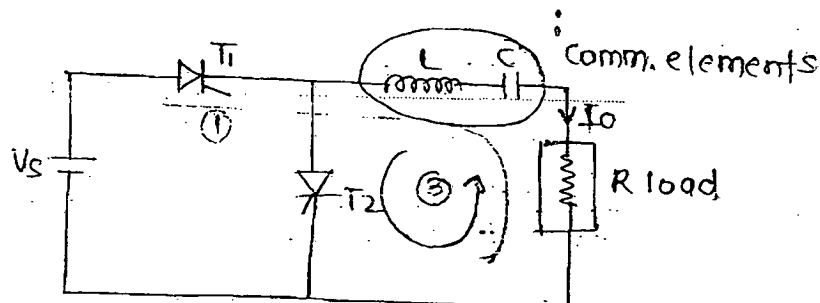
mode(3) →

(at the end of mode 2 → becomes 0)

* (3.) The commutating capacitance limits the max^m freq. of inverter

$$f_{max} = \frac{1}{4RC}$$

* Series Inverter →



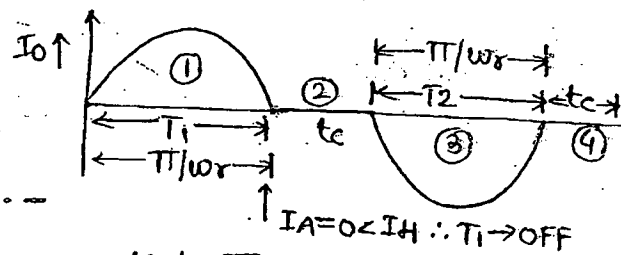
* Here RLC should satisfy underdamped condn

* Here the commutating device is series Hence called series inverter

$$I = \frac{V_s}{\omega_r L} e^{-\delta t} \sin \omega_r t$$

$$\omega_r = \sqrt{\frac{1}{LC} - \frac{R^2}{4L^2}} \quad \delta = \frac{R}{2L} \quad (\delta = \text{damping factor})$$

mode(2) In this mode we have to provide comm. time for the outgoing thy. T1 before the incoming thy. T2 is switched.
($t_c > t_q$)



$$\omega_r t = \pi$$

$$t = \pi/\omega_r$$

$$T = 2\left(\frac{\pi}{\omega_r} + t_c\right)$$

$$f = \frac{1}{2\left(\frac{\pi}{\omega_r} + t_c\right)}$$

$$f_{max} = \frac{1}{2\left(\frac{\pi}{\omega_r} + t_c\right)}$$

For ideal thy

$$t_q = 0$$

$$f_{max} = \frac{\omega_r}{2\pi}$$

$$f_{max} < \omega_r$$

* At low freq, harmonic distortion is higher. Therefore series inverter is not beneficial at low freq.

Resonant Converters → In this conf Comm. takes place at current 0 (or) voltage 0.
(G31 Bhimra)

! This reduce the switching power loss even at high freq.

* If comm. takes place at current 0 then it is known as 0 current switching (ZCS)

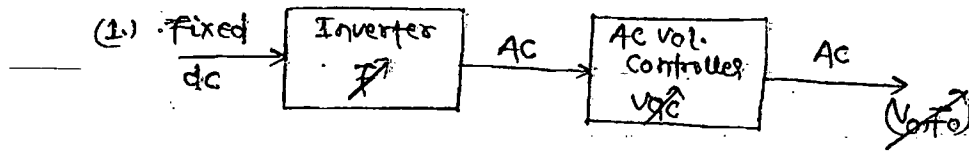
* If comm. takes place at vol. 0 then it is known as 0 Vol. switching (ZVS)

! In this conf we must use LC elements for getting current 0 (or) voltage 0.

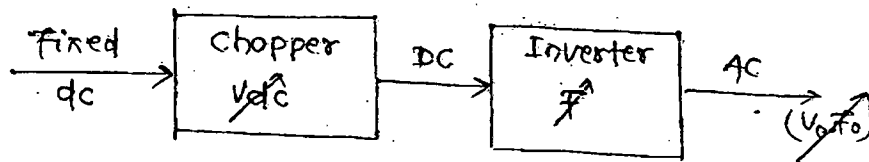
Advantage of Series inverter → In series inverter comm. takes place at current 0 & this minimise the switching power loss even at high freq.

Voltage Control of Inverters →

(1) External Control →



(2)



Drawback → As the no. of stages increases there is an increase in additional power loss along with the size & weight of the equipment.

(2) The filtering requirement becomes costlier due to the increased in harmonics as the no. of stages increased.

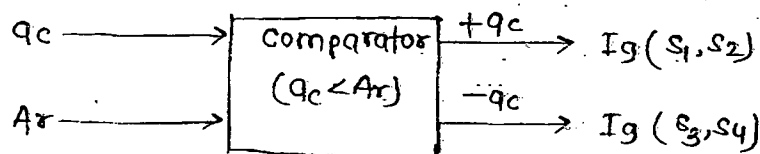
*

(2) Internal Vol. Control using PWM methods →

Advantage → (1) We can control the vol. within the inverter itself.

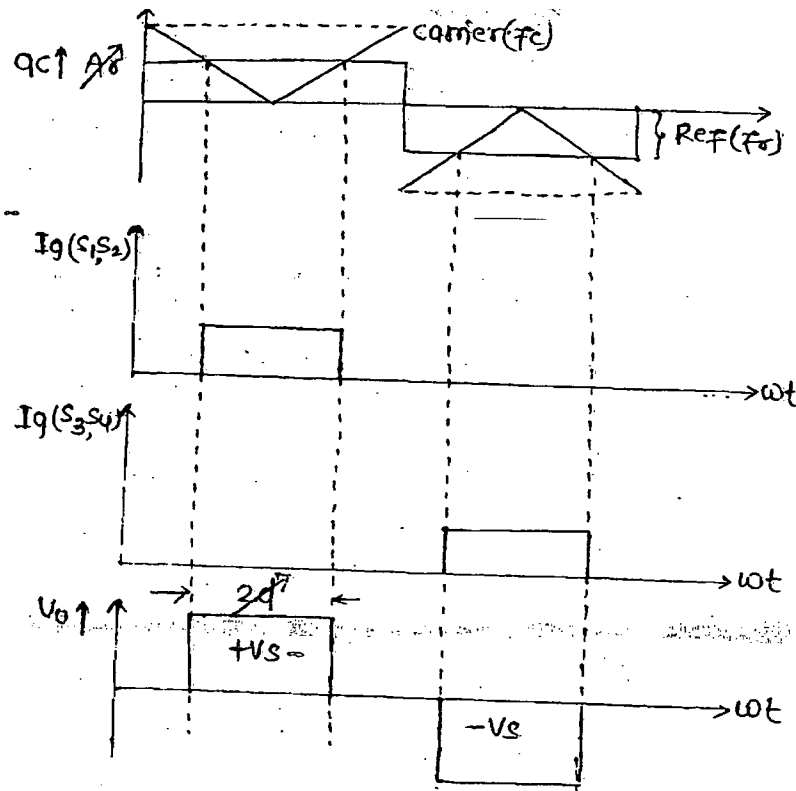
(2) We can eliminate some of the lower order harmonics & this improves the quality of o/p waveform.

(a) Single pulse width modⁿ tech. → Let us realize this PWM tech. For 1 ϕ Full bridge inverter:



$$V_o \hat{r} = V_s \left(\frac{2d}{\pi} \right)^{1/2}$$

$2d$ → total pulse width in each $1/2$ cycle



$$V_o = \sum_{n=1,3,5,\dots}^{\infty} \frac{4V_s}{n\pi} \sin \frac{n\pi}{2} \cdot \sin nd \cdot \sin n\omega t$$

$$V_{on} = \frac{4V_s}{n\pi} \sin \frac{n\pi}{2} \sin nd \cdot \sin n\omega t$$

$$V_{on} = 0, \text{ if } nd = \pi, 2\pi, 3\pi, \dots$$

$$d = \frac{\pi}{n}, \frac{2\pi}{n}, \frac{3\pi}{n}$$

$$2d = \frac{2\pi}{n}, \frac{4\pi}{n}, \frac{6\pi}{n}, \dots$$

Valid only if $2d \leq \pi$
condⁿ to eliminate the harmonic

Ques → What is the pulse width req. to eliminate the 3rd harmonic?

Ans. → * To eliminate the 3rd harmonic...

$$2d = \frac{2\pi}{3}, \frac{4\pi}{3}, \frac{6\pi}{3}$$

$$2d = \frac{360}{3}$$

$$2d = 120^\circ$$

* To eliminate the 5th harmonic.

$$2d = \frac{2\pi}{5}, \frac{4\pi}{5}, \frac{6\pi}{5}$$

$$2d = \frac{2\pi}{5}, \frac{4\pi}{5}$$

There are only 2 options to eliminate the 5th harmonics

$$2d = 72^\circ, 144^\circ$$

* Here we can eliminate the selected harmonics depending upon the width of the pulse.

* For eliminating the low order harmonics (3rd) there is only one option.

* so there is many options to eliminate the higher order harmonics.

$$V_{on} = \frac{2\sqrt{2}}{n\pi} V_s \sin nd$$

$$V_{o1} = \frac{2\sqrt{2}}{\pi} V_s \sin d$$

$$g = \frac{V_{o1}}{V_{or}} = \frac{2\sqrt{2} V_s \sin d}{V_s \left(\frac{2d}{\pi}\right)^{1/2}}$$

$$g = \frac{2\sqrt{2} \sin d}{\sqrt{(2d) \cdot \pi}}$$

Radians

$$THD = \sqrt{\left(\frac{1}{g^2} - 1\right)}$$

eg:- Let $2d = \frac{2\pi}{3} \text{ rad} = 120^\circ$

$$g = \frac{2\sqrt{2} \sin d}{\sqrt{(2d) \cdot \pi}} = \frac{2\sqrt{2} \sin 60^\circ}{\sqrt{\left(\frac{4\pi}{3}\right) \cdot \pi}} = \frac{3}{\pi}$$

$$THD = 31\%$$

Whenever the even & 3rd order harmonics is not present then always

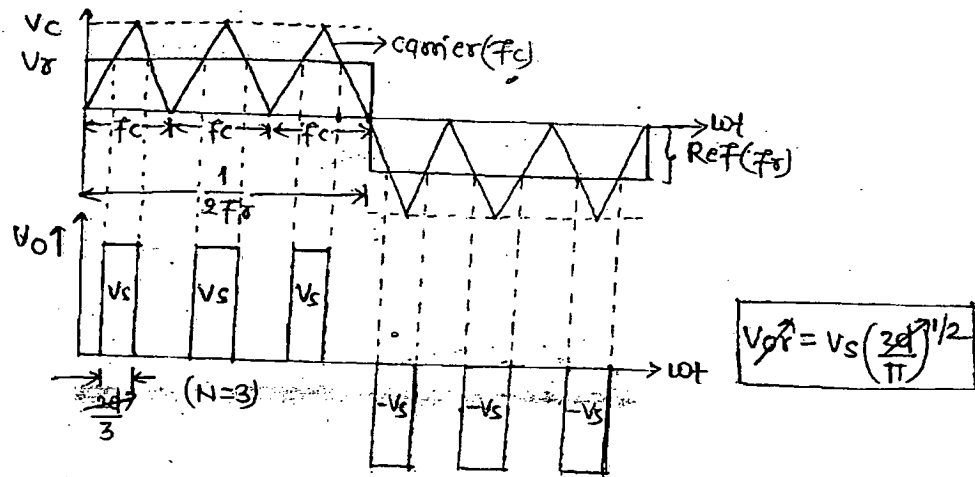
$$g = \frac{3}{\pi} \quad THD = 31\%$$

So by using PWM in 1 ϕ VSI THD = 31%

$$2\phi = 120^\circ$$

* We are using V-shape carrier, but if we use inverted V then the result is same.
V-shape carrier [carrier is high]

(2) Multiple PWM tech. $\rightarrow$ 3 pulse



$$\frac{3}{f_c} = \frac{1}{2f_r} \quad \therefore 3 = \frac{f_c}{2f_r}$$

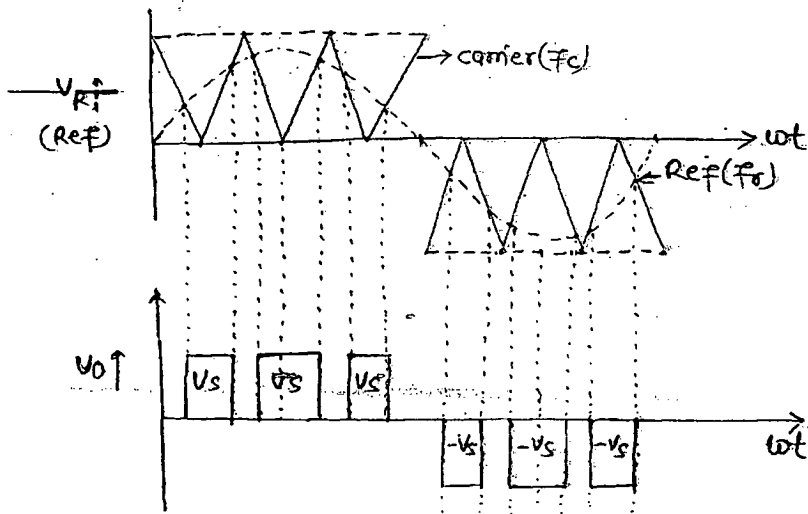
$$N = \frac{f_c}{2f_r}$$

$$\text{Pulse width} = \frac{2d}{N} = \left(1 - \frac{V_r}{V_c} \right) \frac{\pi}{N}$$

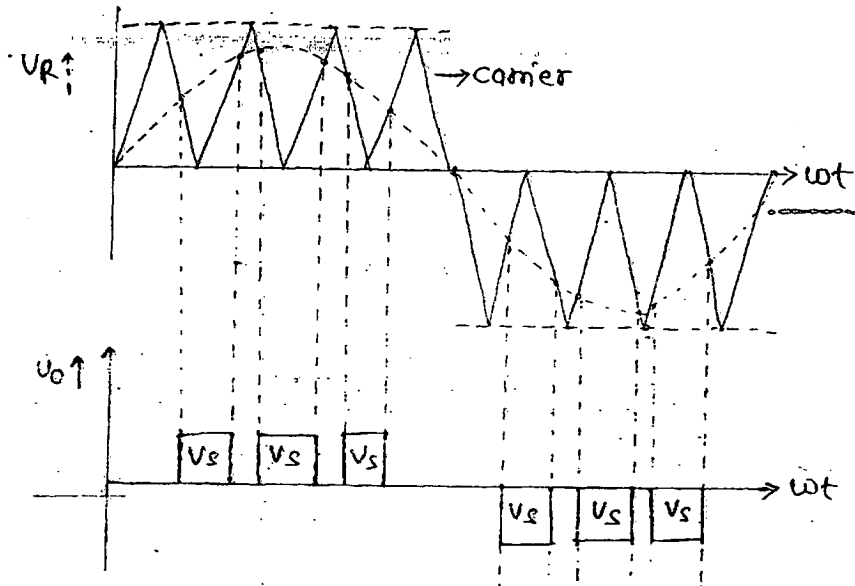
$$PW = \left(1 - \frac{V_r}{V_c} \right) \frac{\pi}{N}$$

3.1 Sinusoidal PWM tech. $\rightarrow$

(I) Peak carrier coincident with zero of ref :-



(II.) Zero of carrier, coincident with zero of ref:-



$$N = \frac{f_c}{2f_r} - 1$$

Note:- Dominant Harmonics $\rightarrow 2N \pm 1$

If $N=3$, $2(3) \pm 1 = 5, 7$

If $N=9$, $2(9) \pm 1 = 17, 19$

modulation index (m_f) = $\frac{V_r}{V_c}$

The domination is shown by lower order it is diff. to filter them.

* We can easily filter the higher order dominant harmonics.

* Therefore in sinusoidal PWM tech, we increase the no. of pulses in each half cycle & increase the order of dominant harmonics. So that they can be filtered very easily.

1 PWM

$$\otimes V_{or} = V_s \left(\frac{2d}{\pi} \right)^{1/2}$$

$$\otimes V_o = \frac{4V_s \sin n\pi}{n\pi} \cdot \frac{\sin nd}{2} (\sin n\omega t)$$

$$\otimes V_{on} = \frac{4V_s \sin n\pi}{n\pi} \cdot \frac{\sin nd}{2} (\sin n\omega t)$$

$$\otimes V_{on} = 0, \text{ ind} = \pi, 2\pi, 3\pi$$

$$d = \frac{\pi}{n}, \frac{2\pi}{n}, \frac{3\pi}{n}$$

$$2d = \frac{2\pi}{n}, \frac{4\pi}{n}, \frac{6\pi}{n}$$

$$\text{If } n=3, 2d = 120^\circ$$

$$n=5, 2d = 72, 144^\circ$$

$$\otimes V_{or} = \frac{4V_s \sin d}{\pi\sqrt{2}}$$

$$V_{o1} = \frac{2\sqrt{2}V_s \sin d}{\pi}$$

$$\otimes g = \frac{V_{or}}{V_{or}} = \frac{2\sqrt{2}V_s \sin d / \pi}{V_s \left(\frac{2d}{\pi} \right)^{1/2}}$$

$$g = \frac{2\sqrt{2} \sin d}{\sqrt{2d}\pi}$$

$$\otimes g = \frac{3}{\pi}, \text{ THD} = 31\%$$

Multi PWM

$$\otimes N = \frac{f_c}{2f_r}$$

$$\otimes PW = \left(1 - \frac{V_a}{V_c} \right) \frac{\pi}{N}$$

Sinusoidal PWM

$$\otimes N = \frac{f_c}{2f_r} - 1$$

$$\otimes \text{Dominant} = 2N \pm 1 \text{ Harmonic}$$